

Fractional-filling Mott domains in two dimensional optical superlattices

P. Buonsante,¹ V. Penna,¹ and A. Vezzani²

¹*Dipartimento di Fisica, Politecnico di Torino and I.N.F.M,
Corso Duca degli Abruzzi 24, I-10129 Torino (ITALIA)*

²*Dipartimento di Fisica, Università degli Studi di Parma, I-43100 Parma (ITALIA)*
(Dated: February 2, 2008)

Ultracold bosons in optical superlattices are expected to exhibit fractional-filling insulating phases for sufficiently large repulsive interactions. On strictly 1D systems, the exact mapping between hard-core bosons and free spinless fermions shows that any periodic modulation in the lattice parameters causes the presence of fractional-filling insulator domains. Here, we focus on two recently proposed realistic 2D structures where such mapping does not hold, i.e. the two-leg ladder and the trimerized kagomé lattice. Based on a *cell* strong-coupling perturbation technique, we provide quantitatively satisfactory phase diagrams for these structures, and give estimates for the occurrence of the fractional-filling insulator domains in terms of the inter-cell/intra-cell hopping amplitude ratio.

PACS numbers: 05.30.Jp, 73.43.Nq, 03.75.Lm 74.81.Fa,

Originally introduced as a toy model of liquid helium trapped in porous media [1], the Bose Hubbard model is nowadays routinely brought to experimental reality in terms of ultracold bosonic atoms trapped in optical or magnetic lattices [2]. The power of this physics tool as a virtually ideal realization of the theoretical model stands in the broad range of parameters and configurations attainable. For instance, the hopping amplitude of the bosons across the lattice sites can be controlled quite directly by varying the strength of the laser beams providing the optical confinement. Additional flexibility comes from the possibility of tuning — and even reversing — the interparticle interactions via Feshbach resonances [3]. Further aspects of ideality are the fact that, to all practical purposes, the system is at zero temperature and isolated from the environment. Thus, for instance, the phononic excitations typical of realistic condensed matter lattice systems are ruled out. This impressive degree of control over the system parameters played a key role in the breakthrough experiment in which the superfluid-insulator quantum phase transition predicted for the Bose-Hubbard model [1] was actually observed for a gas of ultracold atoms trapped in an optical lattice [4].

A great variety of optical lattices can be attained through a suitable choice of the number and setup of the laser beams providing the optic confinement [5]. So far, 1D [6], 2D [7], and 3D [4] Euclidian lattices have been realized, as well as 1D superlattices [8] and quasiperiodic lattices [9]. The progress in optical trapping techniques prompted a great number of proposals for non trivial optical lattices, including periodic geometries [10], quasicrystals [11, 12] and 2D superlattices [13].

The complex periodic geometry of optical superlattices, entailing a multi-band single-particle spectrum, allows for fractional filling insulating domains in the zero temperature phase diagram of superlattice BH models [13, 14, 15, 16]. It has been furthermore observed that such domains may exhibit an unusual loophole shape, as opposed to the roughly triangular shape of the customary Mott lobes [17]. So far, the theoretical investigations on

the quantum phase transitions in superlattice BH models focused on 1D systems, where the fractional filling insulating domains can be directly related to the inter-band gaps in the single particle spectrum [17], owing to the mapping between the hard-core boson regime and free spinless fermions [18, 19]. On non strictly 1D structures such mapping does not apply, and therefore the phase diagram cannot be inferred from the single particle spectrum. Qualitative results have been obtained in the extreme regime where the hopping amplitudes among different cells are much smaller than those within the same cell [13]. Quantitative results can be obtained resorting to numerical methods such as quantum Monte Carlo [20, 21] or density matrix renormalization group algorithms [22]. These approaches necessarily address finite systems, whose size has to be sufficiently large to provide a good approximation of the thermodynamic limit. On superlattices the dimensional scaling of the computational demand is made even more serious by the fact that the building blocks are cells comprising several sites, as opposed to single sites. On the other hand, satisfactory quantitative results have been obtained for d -dimensional regular lattices based on analytical [23] and numeric [24] strong-coupling perturbative expansions (SCPE). A similar technique, adapted to the complex periodicity of superlattices [25], has been recently introduced for the study of the 1D structures whose experimental realization is described in Ref. [8].

Here we extend this technique, called *cell* SCPE, to more complex superlattices. We focus on the two realistic structures sketched in Fig. 1, namely the trimerized kagomé lattice (TKL) proposed in Ref. [13] and a two-leg ladder (TLL), which in some sense represents the minimal diversion from strictly 1D systems. Such a structure can be realistically obtained by superimposing a directional confinement on a suitably chosen portion of a 2D optical lattice, as it was done in Ref. [8] in the case of a 1D lattice, or combining simple lattices with different lattice constants, as proposed in Ref. [26]. We observe that the strong interaction regime of the ladder BH Hamilto-

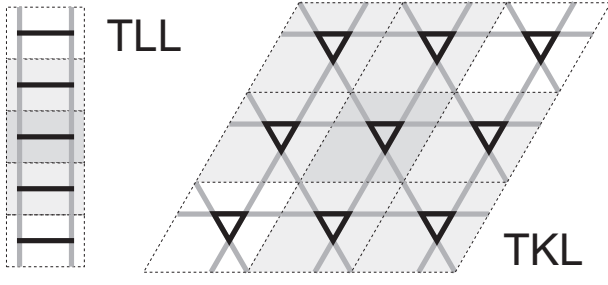


FIG. 1: Cell structure of the TLL (left) and TKL lattice (right). Dark and light thick solid lines represent intra-cell and inter-cell hopping amplitudes, respectively. A light gray shade signals the nearest neighbors of the central cell, which has a darker background. This shows that cell-lattice of the TLL (TKL) is a 1D euclidean lattice (2D triangular lattice).

nian maps onto a spin ladder model, a system that has received wide attention in the literature [27, 28]. This once again shows that ultracold atoms in optical lattices provide a direct realization of condensed matter models over a wide range of model parameters [26].

As expected, we find that the structures we consider exhibit insulating domains at critical fractional fillings of the form k/ℓ , where k is a positive integer and ℓ is the number of sites in the unit cell ($\ell = 2$ for the TLL and $\ell = 3$ for the TKL). Since we assume that there are no energy offsets between the lattice sites, the non integer fillings correspond to loop-hole domains [17]. Our aim is to investigate the conditions for the occurrence of such domains. Before getting into details, let us briefly list our main results. Unlike the 1D case, on the TKL the superlattice structure is not sufficient for the occurrence of fractional-filling domains. That is to say, the inter-cell hopping amplitude has to be sufficiently smaller than the intra-cell amplitude for these insulating domains to occur, despite the fact that an arbitrarily small difference between these amplitudes is sufficient for opening a gap in the single-particle spectrum of the TKL. Conversely, on the TLL our results suggest that fractional filling insulating phases occur even if the single particle spectrum has no gap. These discrepancies are consistent with the fact that on non strictly 1D structures the hard core limit of the Bose-Hubbard model is not equivalent to a free spinless fermion model [18].

Let us now introduce the notation for the superlattice BH Hamiltonian describing the optically trapped ultracold boson systems we are interested into. The spatial arrangement of the unit cells inherent in a superlattice is described by the so-called adjacency matrix A of the cell-lattice, where $A_{cc'}$ is 1 if the cells labeled c and c' are adjacent, and zero otherwise. As it is clear from Fig. 1, the cell lattice is a 1D chain for the TLL, and a triangular lattice for the TKL. The homogeneity of the cell lattice entails that the coordination of the generic cell c is actually cell independent, $z_c = \sum_{c'} A_{cc'} = z$. A generic site of the superlattice can be labeled with two indices,

the first referring to the cell it belongs to, and the second denoting its position within such cell. Thus, the hopping amplitudes across sites belonging to adjacent ℓ -site cells can be described introducing a set of $\ell \times \ell$ matrices $t^{cc'}$. The row index of such matrices refers to the cell denoted by the first superscript, whereas the column index refers to the cell relevant to the second superscript. Symmetry considerations lead to conclude that there are $z/2$ such matrices, and that $t^{c'c} = (t^{cc'})^t$. For instance, in the case of the TLL, where $z = 2$, one has only $t_{ij}^{c,c+1} = t\delta_{ij}$. A further $\ell \times \ell$, symmetric, matrix T_{jh} allows the description of the hopping amplitudes among sites belonging to the same unit cell. Thus, the BH Hamiltonian on a generic superlattice reads

$$H = H_0 + \tau V, \quad H_0 = \sum_c H_c \quad (1)$$

where, introducing the the boson operators at the j^{th} site of the c^{th} cell, $a_{c,j}$, $a_{c,j}^+$ and $n_{c,j} = a_{c,j}^+ a_{c,j}$,

$$H_c = \sum_{j=1}^{\ell} \left[\frac{U}{2} n_{c,j} (n_{c,j} - 1) - (\mu - v_j) n_{c,j} \right] - \sum_{j,h=1}^{\ell} T_{hj} a_{c,j}^+ a_{c,h} \quad (2)$$

refers to an isolated cell, while

$$V = \sum_{c,c'} A_{cc'} \sum_{j,j'=1}^{\ell} t_{jj'}^{cc'} a_{c,j}^+ a_{c',j'} \quad (3)$$

takes into account the interaction among adjacent cells. The parameters $U > 0$, μ and v_j appearing in Eq. (2) are the boson-boson (repulsive) interaction, the chemical potential and the energy offset of the j^{th} site within the unit cell [29]. We observe that the partitioning of a superlattice into a homogeneous lattice of identical unit cells, and hence the arrangement of terms in Eq. (1), is not unique. However, the perturbative approach we are interested into suggests that a convenient choice is such that the inter-cell amplitudes are smaller than the intra-cell amplitudes.

The zero temperature phase diagram of the superlattice BH model in Eq.(1) is standardly obtained in terms of the ground state energies relevant to different fillings [1]. We recall indeed that Hamiltonian H commutes with the total number operator, $\sum_{c,j} n_{c,j}$, and hence it can be studied within a fixed-number sector of the Fock space without loss of generality. Denoting by E_N the ground state energy of H relevant to a population of N bosons, the boundaries of the insulator domain possibly corresponding to a given filling f are standardly obtained as $\mu_{\pm} = \pm(E_{fM \pm 1} - E_{fM})$, where M is the number of sites in the lattice. The insulator domain actually exists if the inequality $\mu_+ > \mu_-$ holds strictly [1].

As we mention above, we provide the insulator domain boundaries $\mu_{\pm}$ in terms of strong coupling expansions for

the ground state energy of Hamiltonian (1), assuming that the inter-cell hopping term in Eq. (3) is the perturbative quantity. As it is easily understood, the eigenvectors and eigenvalues of the (identical) cell Hamiltonians (2) are the key quantities in our perturbative expansions. Denoting by $|k, N\rangle$ the k^{th} eigenstate of the cell Hamiltonian relevant to a population of N bosons and E_k^N the corresponding eigenvalue, the generic eigenstate of the unperturbed Hamiltonian H_0 relevant to a population of $\sum_c N_c$ bosons and the corresponding energy can be written as

$$|\mathbf{k}, \mathbf{N}\rangle = \bigotimes_c |k_c, N_c\rangle_c, \quad E(\mathbf{k}, \mathbf{N}) = \sum_c E_{k_c}^{N_c}, \quad (4)$$

where the subscript c labels the cells. In particular, setting $k_c = 1$ and $N_c = L$, Eq. (4) describes the unperturbed ground state relevant to the fractional filling $f = L/\ell$, where we recall that ℓ denotes the number of sites in each of the identical cells. As we mention above, in order to describe the insulator domain boundaries for such filling, we also need the ground state energies for the so called *defect* states [23], obtained increasing or decreasing the total population by a single boson. Equation (4) gives the correct unperturbed result for such states, provided that the population of one of the cells is increased or decreased by one boson. However, such energy is clearly degenerate, since the population variation can affect any cell. This means that the defect states must be treated according to degenerate perturbation theory. We carried out the expansions up to the second order for both the TLL and the TKL, obtaining the ground state energies for the fractional fillings $f = L/\ell$ and the relevant defect states in terms of the unperturbed cell energies E_k^N and cell matrix elements $\langle k, N | a_h | k', N' \rangle$, where a_h is a generic annihilation operator appearing in Eq. (3) and $N, N' = L - 2, L - 1, L, L + 1, L + 2$. The form of the perturbative terms is quite similar to those described in the appendix of Ref. [25] in the case of 1D superlattices, although more complex, essentially due to the more complex topology of the structures in Fig. 1. Note indeed that the perturbative term in Eq. (3) is such that a boson operator at a given site of a cell may be involved in more than one inter-cell hopping, unlike the 1D case. This (not excessive) increase in complexity is greatly rewarded by a very low computational effort, mostly required by the complete diagonalization of the cell Hamiltonian (2) for a few values of the cell population. Since the cells of the structures in Fig. 1 comprise just two and three sites, we are able to provide satisfactory quantitative results at a negligible computational cost also for insulator domains relevant to fillings that would be prohibitive for brute force numerical methods such as quantum Monte Carlo or density matrix renormalization group simulations. More in general, the portion of phase diagram of a superlattice accessible to our perturbative technique depends only on the number of sites within a unit cell, and not by the topology or dimensionality of the cell lattice. We checked the correctness

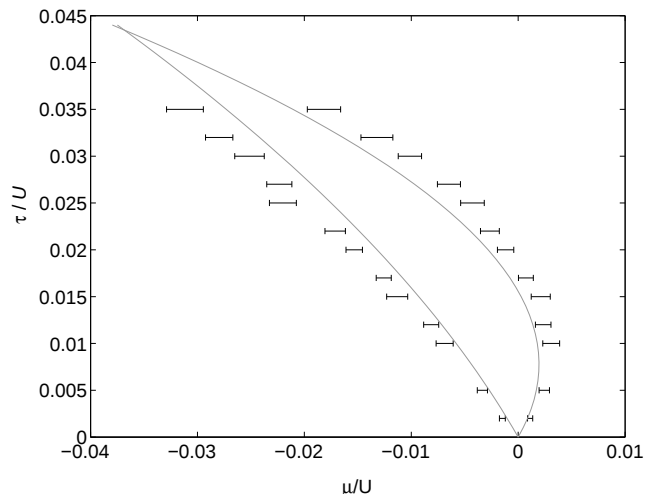


FIG. 2: Half-filling insulator domain for a TLL with intra-cell hopping amplitudes τ and inter-cell hopping amplitudes $\tau/2$. The 2nd order cell SCPE result (solid lines) is compared to quantum Monte Carlo simulations for a TLL comprising 50 rungs (errorbars).

of our perturbative results against brute force numeric results (Lanczos or quantum Monte Carlo algorithm) on small periodic ladder and kagomé lattices (comprising up to 9 cells). Our formulas hold for the most generic superlattice described by Eqs. (1)-(3). This means that the intra-cell hopping amplitudes, as well as the energy offsets v_k , may be different from each other. Furthermore, there can be $z/2$ different inter-cell hopping amplitudes, where z is the coordination number of the cell lattice. Here we assume that $v_k = 0$, so that the fractional filling insulator domains have a loophole shape [17]. Furthermore we assume that all of the intra-cell hopping amplitudes are equal to τ , and all of the inter-cell hopping amplitudes are equal to τ' . In these conditions the presence of loophole domains can be related to a simple parameter, i.e. the hopping ratio τ'/τ , that is basically the perturbative quantity in our expansions. This ratio can be also connected to the energy gap in the single particle spectra of the structures under concern, that on 1D structures bears a strict relation to the presence of loopholes, due to the exact mapping between hard-core bosons and free spinless fermions [17, 18].

In the case of the TLL, the gap in the single particle spectrum disappears for $\tau/\tau' \leq 2$, whereas for the TKL it is present for any $\tau \neq \tau'$. Detailed investigations at half-filling for the ladder and at 1/3-filling for the TKL show that the thresholds for the occurrence of the relevant loophole insulator domains differ from those of the single particle gaps. Actually, Fig. 2 shows that, according to both cell SCPE and quantum Monte Carlo simulations, the half-filling loophole domain of the ladder is still present for $\tau/\tau' = 2$, when the single particle gap is not present any more. The comparison between these results also shows that cell SCPE provide quanti-

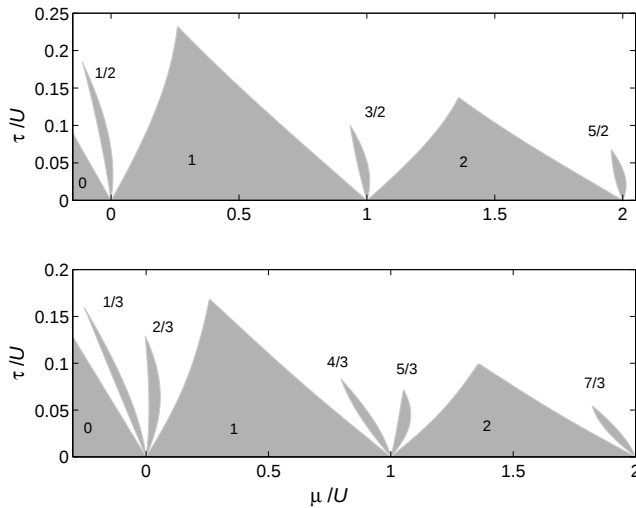


FIG. 3: Phase diagrams for the structures in Fig. 1. Top: TLL with $\tau = 3\tau'$. Bottom: TKL with $\tau = 6\tau'$. The fillings of the insulator domains (gray) are also given in the plot.

tatively satisfactory results also when τ' is a significant fraction of τ , i.e. when the perturbative term is far from being infinitesimal. Furthermore, both cell SCPE and quantum Monte Carlo simulations for hard-core bosons suggest that the half-filling loophole domain of the ladder persists for $\tau/\tau' < 2$, and disappears when the hopping ratio becomes smaller than a finite quantity smaller than 2. This partially agrees with the results reported in Ref. [28] for a spin ladder that maps onto the hard-core limit of our model for a suitable parameter choice.

On the TKL the situation is in some sense reversed, since the loophole domains disappear when a single particle gap is still present. More precisely, the gap is open for any $\tau' < \tau$, but it must be $\tau' < \tau/c$ for the loophole

insulator domains to occur, where $c = c_1 \approx 2.32$ and $c = c_2 \approx 2.87$ according to first and second order perturbative results, respectively. We mention that these values of c are the same for the first three loopholes, relevant to filling $1/3$, $2/3$ and $4/3$. Note that the fact that $c_2 > c_1$ is coherent with our perturbative approach, whose expansion parameter is basically τ'/τ .

We conclude by commenting Fig. 3, which shows the phase diagrams for the structures under investigation as provided by our second order cell strong coupling expansions. The value of the (fixed) hopping ratio τ/τ' is 3 for the TLL (upper panel) and 6 for the TKL (lower panel). Note that, since the hopping amplitude depends exponentially on the strength of the optical lattice, the above ratios correspond to a relatively small modulation of the potential profile of the superlattice. We emphasize that these ratios correspond to an arbitrarily small modulation of the potential profile of the superlattice. Indeed, we recall that $\tau \sim e^{-Ih}$, $\tau' \sim e^{-Ih'}$, where I is the strength of the optical lattice, while h and h' are scaling factors related to the height of the potential barrier between adjacent sites belonging to the same cell or to different cells, respectively [2]. It is hence clear that a sufficiently large I produces the desired ratio, provided that $h < h'$. This suggests that the fractional filling insulating phase can be always reached if the lattice strength is increased while keeping the potential profile fixed. In this respect we emphasize that Figs. 2 and 3 correspond to a slightly different approach, since we assume that τ/U is varied while keeping the ratio τ/τ' fixed. This can be done by adjusting the setup and intensity of the laser beams giving rise to the optical superlattice, at least in principle [8, 15, 17]. However it may prove more convenient to keep the beam configuration fixed (i.e. to fix τ and τ'), while varying the interaction strength U , e.g. via Feshbach resonances [3].

-
- [1] M. P. A. Fisher et al., Phys. Rev. B **40**, 546 (1989).
 - [2] D. Jaksch et al., Phys. Rev. Lett. **81**, 3108 (1998).
 - [3] M. Theis et al., Phys. Rev. Lett. **93**, 123001 (2004).
 - [4] M. Greiner et al., Nature **415**, 39 (2002).
 - [5] P. B. Blakie and C. W. Clark, J. Phys. B **37**, 1391 (2004).
 - [6] F. S. Cataliotti et al., Science **293**, 843 (2001).
 - [7] M. Greiner et al., Phys. Rev. Lett. **87**, 160405 (2001).
 - [8] S. Peil et al., Phys. Rev. A **67**, 051603(R) (2003).
 - [9] L. Guidoni et al., Phys. Rev. Lett. **79**, 3363 (1997).
 - [10] L. Amico et al., e-print cond-mat/0501648.
 - [11] L. Sanchez-Palencia and L. Santos, e-print cond-mat/0502529.
 - [12] M. Salerno, e-print cond-mat/0504401.
 - [13] L. Santos et al., Phys. Rev. Lett. **93**, 030601 (2004).
 - [14] O. I. Motrunich and T. Senthil, Phys. Rev. Lett. **89**, 277004 (2002).
 - [15] R. Roth and K. Burnett, Phys. Rev. A **68**, 023604 (2003).
 - [16] P. Buonsante and A. Vezzani, Phys. Rev. A **70**, 033608 (2004).
 - [17] P. Buonsante et al., Phys. Rev. A **70**, 061603(R) (2004).
 - [18] M. Girardeau, J. Math. Phys. **1**, 516 (1960).
 - [19] M. A. Cazalilla, Phys. Rev. A **67**, 053606 (2003).
 - [20] G. G. Batrouni et al., Phys. Rev. Lett. **65**, 1765 (1990).
 - [21] V. A. Kashurnikov et al., JETP Lett. **64**, 99 (1996).
 - [22] T. D. Kühner and H. Monien, Phys. Rev. B **58**, R14741 (1998).
 - [23] J. K. Freericks and M. Monien, Europhys. Lett. **26**, 545 (1994).
 - [24] N. Elstner and H. Monien, Phys. Rev. B **59**, 12184 (1999).
 - [25] P. Buonsante et al., e-print cond-mat/0503232.
 - [26] J. J. García-Ripoll et al., Phys. Rev. Lett. **93**, 250405 (2004).
 - [27] E. Dagotto, Rep. Prog. Phys. **62**, 1525 (1999).
 - [28] T. Vekua et al., Phys. Rev. B **67**, 064419 (2003).
 - [29] Since the cells are identical, the energy offsets v_k and the hopping amplitudes T_{hk} do not depend on the cell index.